NCE60P04R

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE60P04R uses advanced trench technology and design to provide excellent $R_{\text{DS(ON)}}$ with low gate charge .This device is well suited for use as a load switch or in PWM applications.

General Features

V_{DS} =-60V,I_D =-4.3A

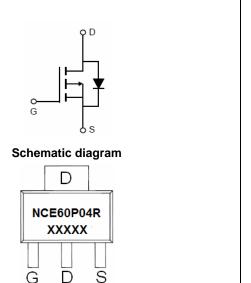
 $R_{DS(ON)}$ <120m Ω @ V_{GS} =-10V

 $R_{DS(ON)}$ <170m Ω @ V_{GS} =-4.5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

Application

- Load switch
- PWM application



SOT-223 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE60P04R	NCE60P04R	SOT-223-3L	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	-4.3	Α
Pulsed Drain Current	I _{DM}	-20	Α
Maximum Power Dissipation	P _D	3.1	W
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	40.3	°C/W

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V,V _{GS} =0V	-	-	-1	μA



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Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=-250\mu A$	-1.5	-2.2	-3.0	V
Drain-Source On-State Resistance	D	V_{GS} =-10V, I_D =-4A	-	106	120	mΩ
Diain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =-4.5V, I_D =-3A	-	135	170	mΩ
Forward Transconductance	g FS	V_{DS} =-5 V , I_{D} =-4 A	-	10	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C_{lss}	V_{DS} =-30 V , V_{GS} =0 V ,	-	930	-	PF
Output Capacitance	C _{oss}	V _{DS} =-30V,V _{GS} =0V, F=1.0MHz	-	85	-	PF
Reverse Transfer Capacitance	C_{rss}	F = 1.0WH12	-	35	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	8	-	nS
Turn-on Rise Time	t _r	V_{DD} =-30V, R_L =7.5 Ω ,	-	4	-	nS
Turn-Off Delay Time	$t_{d(off)}$	V_{GS} =-10 V , R_{G} =3 Ω	-	32	-	nS
Turn-Off Fall Time	t _f		-	7	-	nS
Total Gate Charge	Qg	V = 20 L = 4A	-	25	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-30, I_{D} =-4A, V_{GS} =-10V	-	3	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} 10V	-	7	-	nC
Drain-Source Diode Characteristics	<u>.</u>					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-4A	-		-1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-4.3	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =- 4A	-	25		nS
Reverse Recovery Charge	Qrr	$di/dt = -100A/\mu s^{(Note3)}$	-	31		nC

Notes:

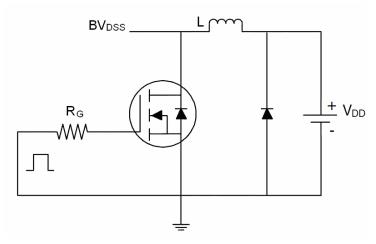
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production

Pb Free Product

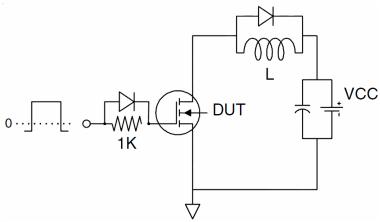


Test Circuit

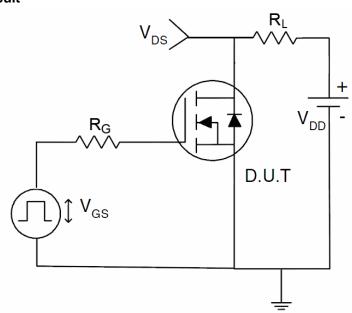
1) E_{AS} test Circuit



2) Gate charge test Circuit



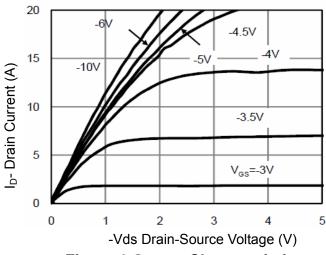
3) Switch Time Test Circuit

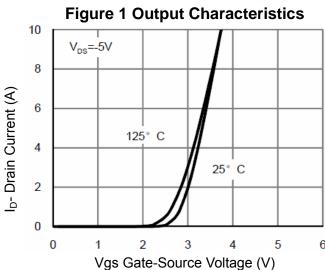


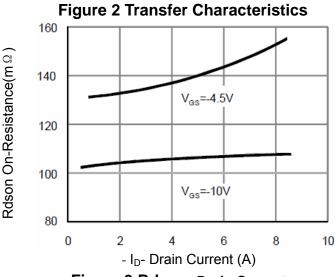
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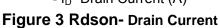


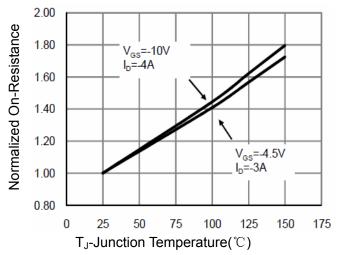
Typical Electrical and Thermal Characteristics (Curves)



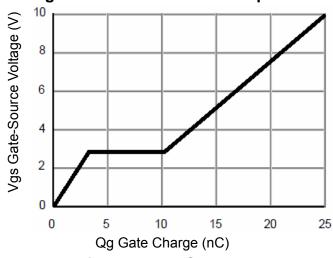


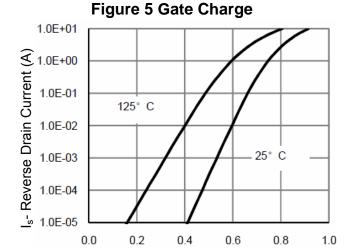




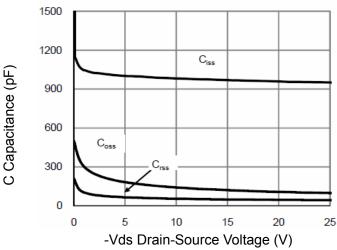








-Vsd Source-Drain Voltage (V) Figure 6 Source- Drain Diode Forward



BV_{DSS} (norm) V_{GS}=0 1.2 1.1 1.0 1.0 0.9 0.8 -50 0 50 100 T_J(°C) T_J-Junction Temperature(°C)

Figure 9 BV_{DSS} vs Junction Temperature

(Y)

4

3

0

25

50

75

100

125

150

175

T_J-Junction Temperature(°C)

Figure 10 ID Current De-rating



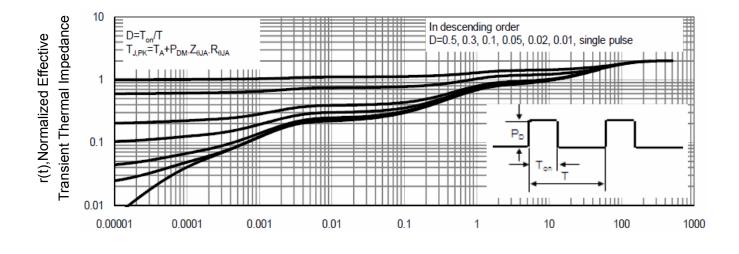


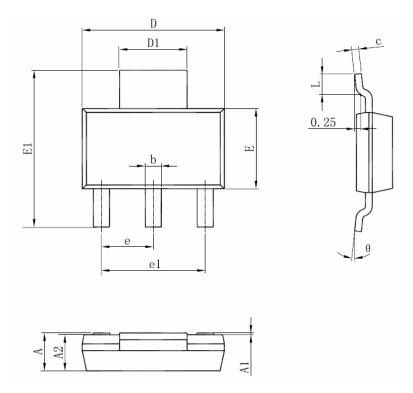
Figure 11 Normalized Maximum Transient Thermal Impedance

Square Wave Pluse Duration(sec)

Pb Free Product



SOT-223 Package Information



Coumb a I	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.520	1.800	0.060	0.071	
A1	0.000	0.100	0.000	0.004	
A2	1.500	1.700	0.059	0.067	
b	b 0.660		0.026	0.032	
С	0.250	0.350	0.010	0.014	
D	6.200	6.400	0.244	0.252	
D1	2.900	3.100	0.114	0.122	
E	3.300	3.700	0.130	0.146	
E1	6.830	7.070	0.269	0.278	
е	2.300	(BSC)	0.091(BSC)	
e1	4.500	4.700	0.177	0.185	
L	0.900	1.150	0.035	0.045	
θ	0°	10°	0°	10°	

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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